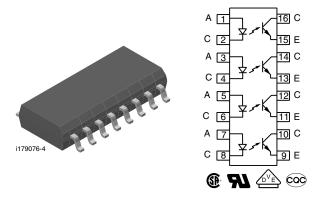




Optocoupler, Phototransistor Output, Quad Channel, SOP-16, Half Pitch Mini-Flat Package



DESCRIPTION

The SFH6916 has a GaAs infrared emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 16 pin 50 mil lead pitch miniflat package. It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

The coupling devices are designed for signal transmission between two electrically separated circuits.

FEATURES

- SOP (small outline package)
- Isolation test voltage, 3750 V_{RMS} (1.0 s)
- High collector emitter voltage, V_{CEO} = 70 V
- Low saturation voltage
- · Fast switching times
- Temperature stable
- Low coupling capacitance
- End stackable, 0.050" (1.27 mm) spacing
- Material astronometrical Foundations of a

 Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ROHS COMPLIANT HALOGEN FREE GREEN

(5-2008)

AGENCY APPROVALS

- UL1577, file no. E52744 system code U
- CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-5 (VDE 0884)
- CQC GB4943.1-2011 (suitable for installation altitude below 2000 m)

ORDERING I	NFORMAT	TION					
S	F	Н	6	9	1	6	SOP-16
			PART NUMBER				
AGENCY CERTIFIED/PACKAGE				С	TR (%)		
UL, cUL				50) to 300		
SOP-16, quad channel				S	FH6916		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		V_{R}	6	V				
DC forward current		I _F	50	mA				
Surge forward current	t _p ≤ 10 μs	I _{FSM}	2.5	Α				
Total power dissipation		P _{diss}	80	mW				
OUTPUT								
Collector emitter voltage		V _{CE}	70	V				
Emitter collector voltage		V _{EC}	7	V				
Collector current		I _C	50	mA				
Collector current	t _p = 1.0 ms	I _C	100	mA				
Total power dissipation per channel		P _{diss}	150	mW				



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
COUPLER							
Isolation test voltage between emitter and detector	t = 1.0 s	V _{ISO}	3750	V_{RMS}			
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω			
isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω			
Storage temperature range		T _{stg}	- 55 to + 125	°C			
Ambient temperature range		T _{amb}	- 55 to + 100	°C			
Junction temperature		Tj	100	°C			
Soldering temperature (1)	max. 10 s dip soldering distance to seating plane ≥ 1.5 mm		260	°C			
Total power dissipation		P _{tot}	700	mW			

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	I _F = 5 mA	V_{F}		1.15	1.4	V		
Reverse current	V _R = 6 V	I _R		0.01	10	μA		
Capacitance	Co	Co		14		pF		
Thermal resistance		R _{thja}		1000		K/W		
OUTPUT								
Collector emitter leakage current	V _{CE} = 20 V	I _{CEO}			100	nA		
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz	C _{CE}		2.8		pF		
Thermal resistance		R _{thja}		500		K/W		
COUPLER								
Collector emitter saturation voltage	$I_F = 20 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}		0.1	0.4	V		
Coupling capacitance	f = 1 MHz	C _C		1		pF		

Note

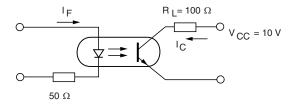
• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

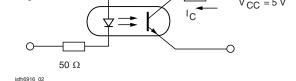
CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER TEST CONDITION SYMBOL MIN. TYP. MAX. UNIT						
Current transfer ratio	$I_F = 5 \text{ mA}, V_{CC} = 5 \text{ V}$	CTR	50		300	%



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SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
NON-SATURATED								
Rise time	I_C = 2 mA, V_{CC} = 10 V, R_L = 100 Ω	t _r		4		μs		
Fall time	$I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V}, R_L = 100 \Omega$	t _f		3		μs		
Turn-on time	I_C = 2 mA, V_{CC} = 10 V, R_L = 100 Ω	t _{on}		5		μs		
Turn-off time	I_C = 2 mA, V_{CC} = 10 V, R_L = 100 Ω	t _{off}		4		μs		
SATURATED								
Rise time	I_F = 16 mA, V_{CC} = 5 V, R_L = 1.9 $k\Omega$	t _r		15		μs		
Fall time	$I_F = 16$ mA, $V_{CC} = 5$ V, $R_L = 1.9$ k Ω	t _f		0.5		μs		
Turn-on time	$I_F = 16$ mA, $V_{CC} = 5$ V, $R_L = 1.9$ k Ω	t _{on}		1		μs		
Turn-off time	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1.9 \text{ k}\Omega$	t _{off}		30		μs		





 $R_I = 1.9 \text{ k}\Omega$

Fig. 1 - Switching Operation (without Saturation)

Fig. 2 - Switching Operation (with Saturation)

SAFETY AND INSULATION RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic classification (according to IEC 68 part 1)				55/100/21				
Comparative tracking index		CTI	175		399			
Peak transient overvoltage		V _{IOTM}	6000			V		
Peak insulation voltage		V _{IORM}	707			V		
Safety rating - power output		P _{SO}			350	mW		
Safety rating - input current		I _{SI}			150	mA		
Safety rating - temperature		T _{SI}			175	°C		
Creepage distance			5			mm		
Clearance distance			5			mm		

Note

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As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

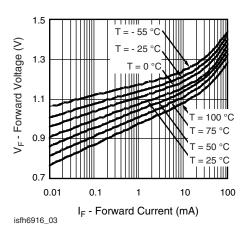


Fig. 3 - Diode Forward Voltage vs. Forward Current

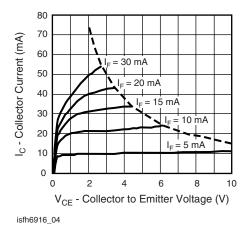


Fig. 4 - Collector Current vs. Collector Emitter Voltage

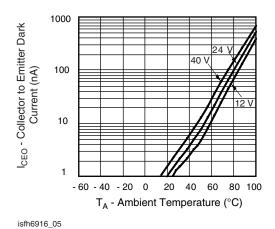


Fig. 5 - Collector to Emitter Dark Current vs. Ambient Temperature

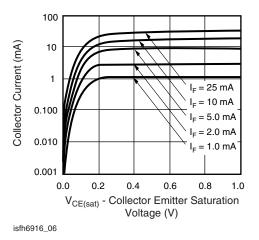


Fig. 6 - Collector Current vs. Collector Emitter Saturation Voltage

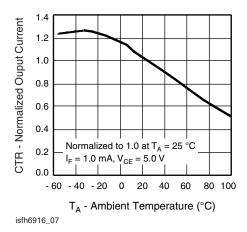


Fig. 7 - Normalized Output Current vs. Ambient Temperature

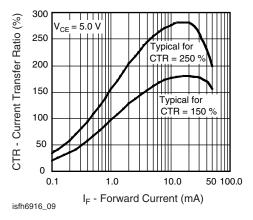
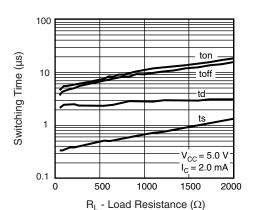


Fig. 8 - Current Transfer Ratio vs. Forward Current





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Fig. 9 - Switching Time vs. Load Resistance

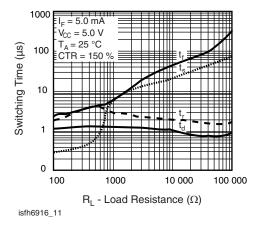


Fig. 10 - Switching Time vs. Load Resistance

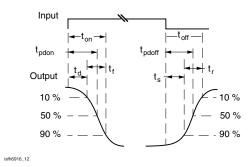
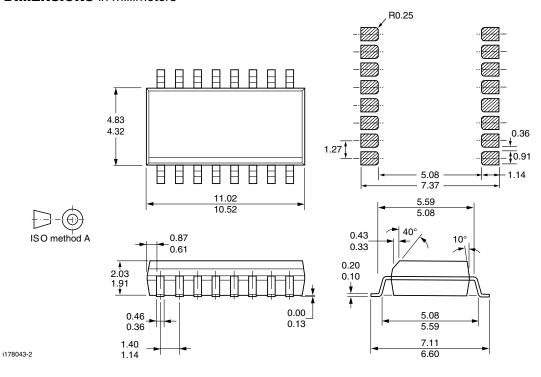


Fig. 11 - Switching Time Measurement

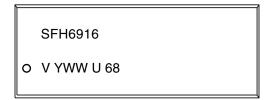


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PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING



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